

Description

The HXY20N10D uses advanced trench technology to provide excellent R_{DS(ON)}, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a

Battery protection or in other Switching application.



TO-252-2L

General Features

 $V_{DS} = 100V I_{D} = 20A$

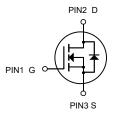
 $R_{DS(ON)}$ < 87 m Ω @ V_{GS} =10V

Application

Battery protection

Load switch

Uninterruptible power supply



N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
HXY20N10D	TO252-2L	20N10 XXX YYYY	2500

Absolute Maximum Ratings Tc=25℃ unless otherwise noted

Symbol	ymbol Parameter		Units	
V _{DS}	Drain-Source Voltage	100	V	
Vgs	Gate-Source Voltage	±20	V	
I _D @T _C =25°C	Continuous Drain Current, V _{GS} @ 10V ¹	20	А	
I _D @T _C =100°C	Continuous Drain Current, V _{GS} @ 10V ¹	10	А	
I _D @T _A =25°C	Continuous Drain Current, V _{GS} @ 10V ¹	5	А	
I _D @T _A =70°C	Continuous Drain Current, V _{GS} @ 10V ¹	3.4	А	
Ірм	Pulsed Drain Current ²	А		
EAS	Single Pulse Avalanche Energy ³ 6.1		mJ	
las	Avalanche Current 15		Α	
P _D @T _C =25°C	Total Power Dissipation ⁴ 34.7		W	
P _D @T _A =25°C	Total Power Dissipation ⁴	2	W	
Тѕтс	Storage Temperature Range -55 to 150		°C	
TJ	Operating Junction Temperature Range -55 to 150		°C	
Reja	Thermal Resistance Junction-ambient ¹ 62		°C/W	
R _θ JC	Thermal Resistance Junction-Case ¹ 3.6			



Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	100			V
△BV _{DSS} /△T	BVDSS Temperature Coefficient	Reference to 25°C , I _D =1mA		0.098		V/°C
Danier	Static Drain-Source On-Resistance ²	V _{GS} =10V , I _D =10A		80	87	mΩ
R _{DS(ON)}	Static Drain-Source On-Resistance	V _{GS} =4.5V , I _D =8A		95	105	mΩ
V _{GS(th)}	Gate Threshold Voltage		1.0		2.5	V
$\triangle V_{GS(th)}$	V _{GS(th)} Temperature Coefficient	VGS-VDS , ID -250UA		-4.57		mV/°C
1	Drain-Source Leakage Current	V _{DS} =80V , V _{GS} =0V , T _J =25°C			1	
I _{DSS}		V _{DS} =80V , V _{GS} =0V , T _J =55°C			5	uA
I _{GSS}	Gate-Source Leakage Current	V _{GS} =±20V , V _{DS} =0V			±100	nA
gfs	Forward Transconductance	V _{DS} =5V , I _D =10A		13		S
R_g	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz		2		Ω
Qg	Total Gate Charge (10V)			26.2		
Q _{gs}	Gate-Source Charge	V _{DS} =80V , V _{GS} =10V , I _D =10A		4.6		nC
Q _{gd}	Gate-Drain Charge			5.1		
$T_{d(on)}$	Turn-On Delay Time			4.2		
Tr	Rise Time	V_{DD} =50V , V_{GS} =10V , R_{G} =3.3 Ω		8.2		
$T_{d(off)}$	Turn-Off Delay Time	I _D =10A		35.6		ns
T _f	Fall Time			9.6		
Ciss	Input Capacitance			1535		
Coss	Output Capacitance	V _{DS} =15V , V _{GS} =0V , f=1MHz		60		pF
Crss	Reverse Transfer Capacitance			37		

Diode Characteristics

Symbol	Parameter	Conditions		Тур.	Max.	Unit
ls	Continuous Source Current ^{1,5}	\\ -\\ -0\\ Farra Current			20	Α
Ism	Pulsed Source Current ^{2,5}	_S =V _D =0V , Force Current			30	Α
V _{SD}	Diode Forward Voltage ² V _G	_{9S} =0V , I _S =1A , T _J =25°C			1.2	V
t _{rr}	Reverse Recovery Time			37		nS
Qrr	Reverse Recovery Charge	=10A , dl/dt=100A/µs , T _J =25°C		27.3		nC

Note

- 1.The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
- 2.The data tested by pulsed , pulse width \leq 300us , duty cycle \leq 2%
- 3.The EAS data shows Max. rating . The test condition is V_{DD} =25V, V_{GS} =10V,L=0.1mH, I_{AS} =11A
- 4.The power dissipation is limited by 150°C junction temperature
- 5.The data is theoretically the same as I_D and I_{DM}, in real applications, should be limited by total power dissipation.



Typical Characteristics

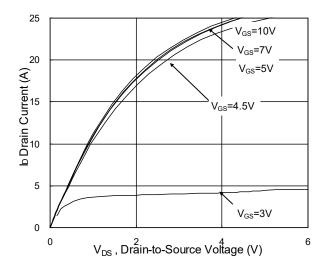


Fig.1 Typical Output Characteristics

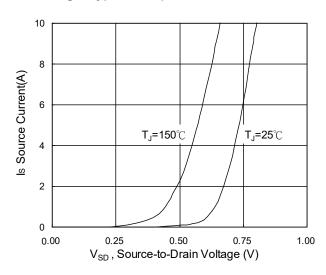


Fig.3 Forward Characteristics Of Reverse

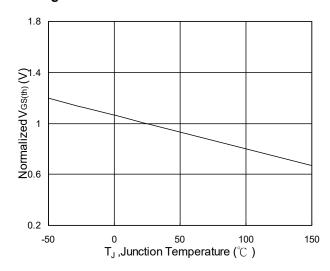


Fig.5 Normalized $V_{\text{GS(th)}}$ vs. T_{J}

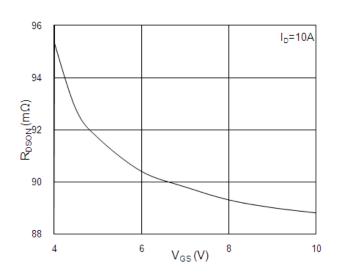


Fig.2 On-Resistance vs. Gate-Source

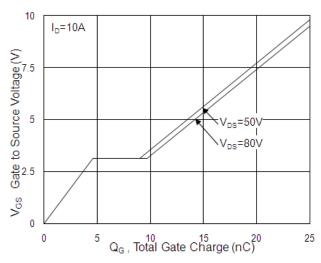


Fig.4 Gate-Charge Characteristics

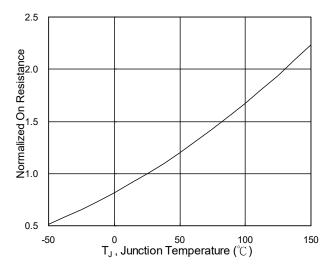
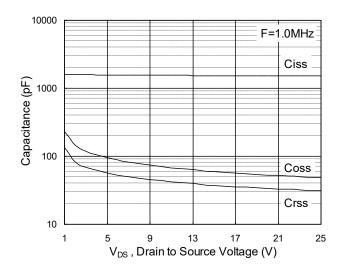


Fig.6 Normalized R_{DSON} vs. T_J





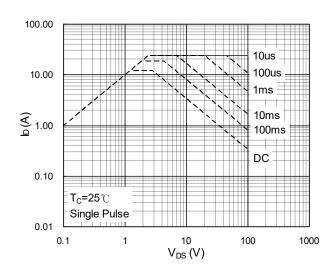


Fig.7 Capacitance

Fig.8 Safe Operating Area

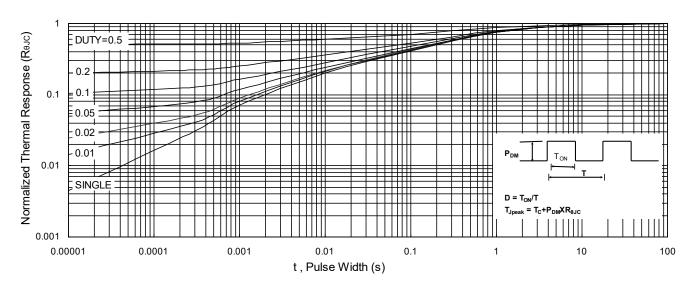
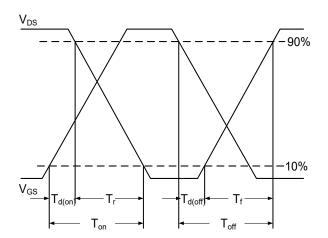
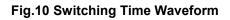


Fig.9 Normalized Maximum Transient Thermal Impedance





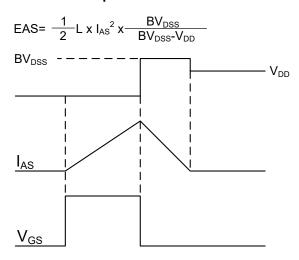
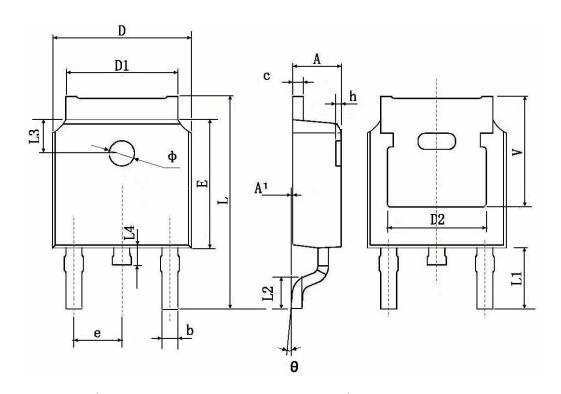


Fig.11 Unclamped Inductive Switching Waveform



TO-252-2L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	0.483	0.483 TYP. 0.190 TYP.		0.190 TYP.	
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900	2.900 TYP.		TYP.	
L2	1.400	1.700	0.055	0.067	
L3	1.600	TYP.	0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350	TYP.	0.211 TYP.		



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